P25LA12SL

Power MOSFETs 120V, 25A, N-channel

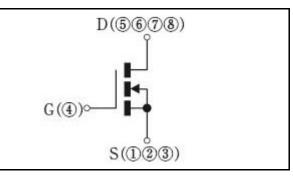
Feature

- N-channel
- Small SMD
- Low Ron
- 4.5V Gate Drive
- Low Capacitance
- Halogen free
- Pb free terminal
- RoHS:Yes

OUTLINE



Equivalent circuit



Absolute Maximum Ratings (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage temperature	Tstg		-55 to 150	°C
Channel tempertature	Tch		-55 to 150	°C
Drain-source voltage	V _{DSS}		120	V
Gate-source voltage	V _{GSS}		±20	V
Continuous drain current(DC)	Ι _D		25	A
Continuous drain current(Peak)	I _{DP}	Pulse width 10µs, duty=1/100	75	А
Total power dissipation	P _T		142	W
Single avalanche current	I _{AS}	Starting Tch=25°C Tch≦150°C	20	А
Single avalanche energy	E _{AS}	Starting Tch=25°C Tch≦150°C	50	mJ

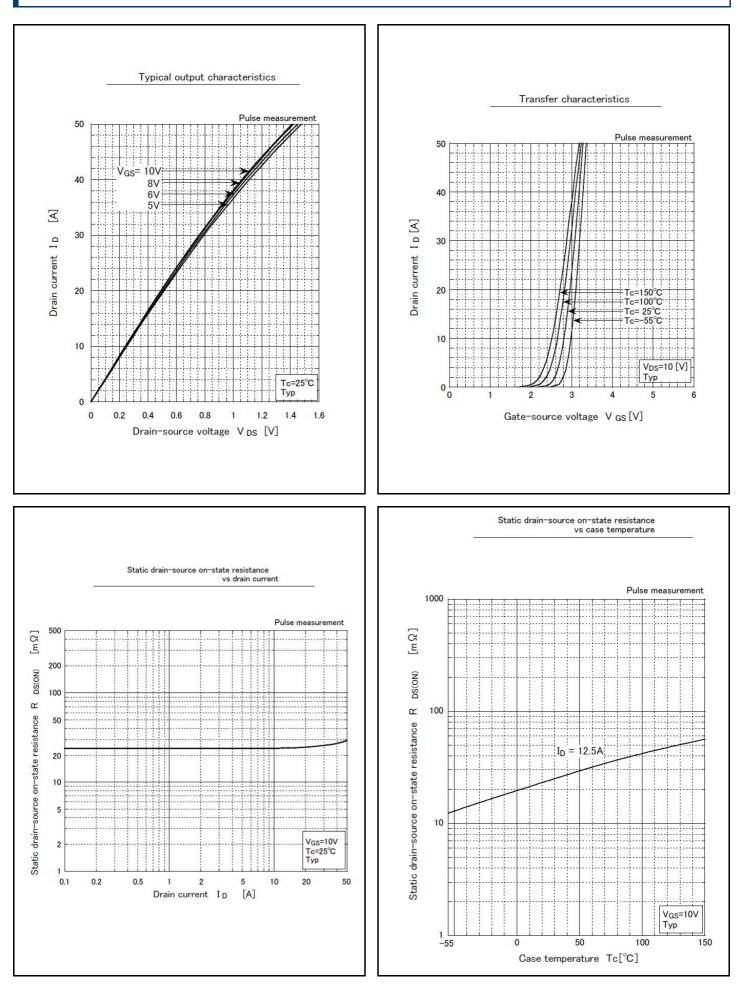
* : See the original Specifications

Electrical Characteristics	(unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions		Ratings		
			MIN	ТҮР	MAX	Unit
Drain-Source breakdown voltage	V _{(BR)DSS}	ID=1mA, VGS=0V	120			V
Zero gate voltage drain current	I _{DSS}	VDS=120V, VGS=0V			1	μA
Gate-source leakage current	I _{GSS}	VGS=±20V, VDS=0V			±0.1	μA
Forward transconductance	g _{fs}	ID=12.5A, VDS=10V	11			S
Static drain-source on-state resistance	R _{DS(ON)}	ID=12.5A, VGS=10V		0.024	0.03	Ω
Static drain-source on-state resistance	R _{DS(ON)}	ID=12.5A, VGS=4.5V		0.026	0.035	Ω
Gate threshold voltage	Vth	ID=1mA, VDS=10V	1.5	2	2.5	V
Source-drain diode forward voltage	V _{SD}	IS=25A, VGS=0V			1.5	V
Thermal resistance	Rth(j-c)	Junction to case, with heatsink			0.88	°C/W
Total gate charge	Qg	VDD=96V, VGS=10V, ID=25A		61		nC
Gate to source charge	Qgs	VDD=96V, VGS=10V, ID=25A		11		nC
Gate to drain charge	Qgd	VDD=96V, VGS=10V, ID=25A		16		nC
Input capacitance	Ciss	VDS=25V, VGS=0V, f=1MHz		2900		pF
Reverce transfer capacitnce	Crss	VDS=25V, VGS=0V, f=1MHz		93		pF
Output capacitance	Coss	VDS=25V, VGS=0V, f=1MHz		194		pF
Turn-on delay time	td(on)	ID=12.5A, RL=4.8Ω, VDD=60V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		4.5		ns
Rise time	tr	ID=12.5A, RL=4.8Ω, VDD=60V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		6.5		ns
Turn-off delay time	td(off)	ID=12.5A, RL=4.8Ω, VDD=60V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		47		ns
Fall time	tf	ID=12.5A, RL=4.8Ω, VDD=60V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		20		ns
Diode reverse recovery time	trr	IF=25A, VGS=0V, di/dt=100A/µs		59		ns
Diode reverse recovery charge	Qrr	IF=25A, VGS=0V, di/dt=100A/µs		136		nC

* : See the original Specifications

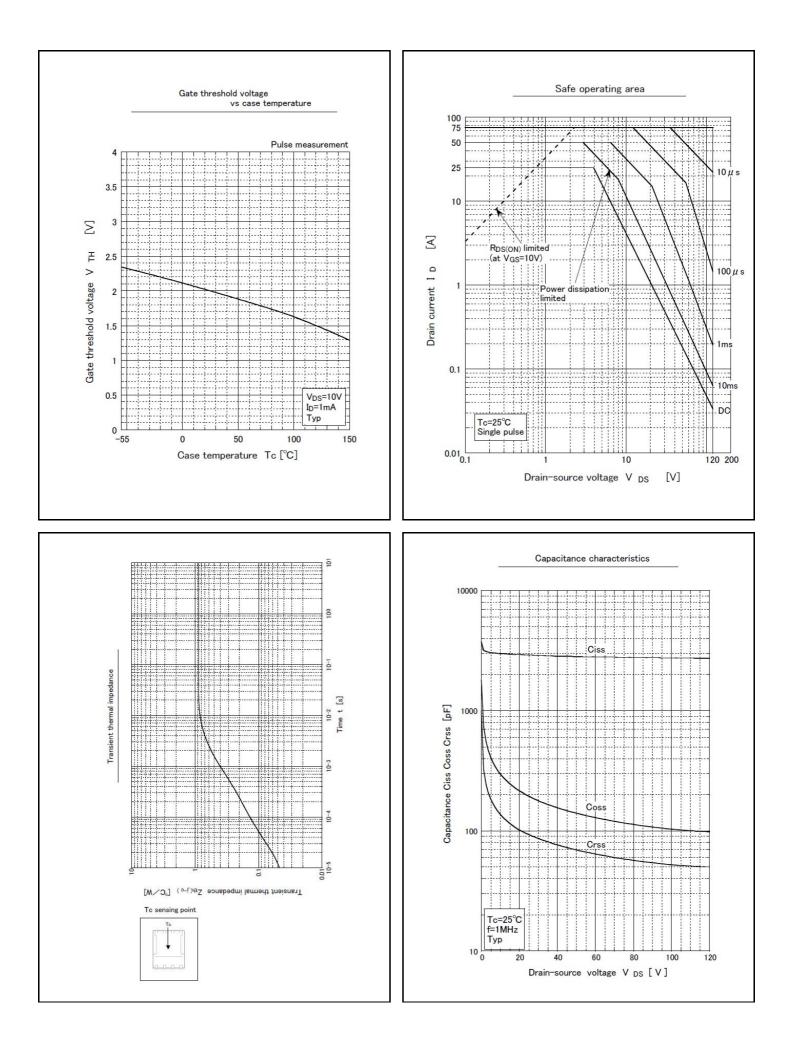
CHARACTERISTIC DIAGRAMS

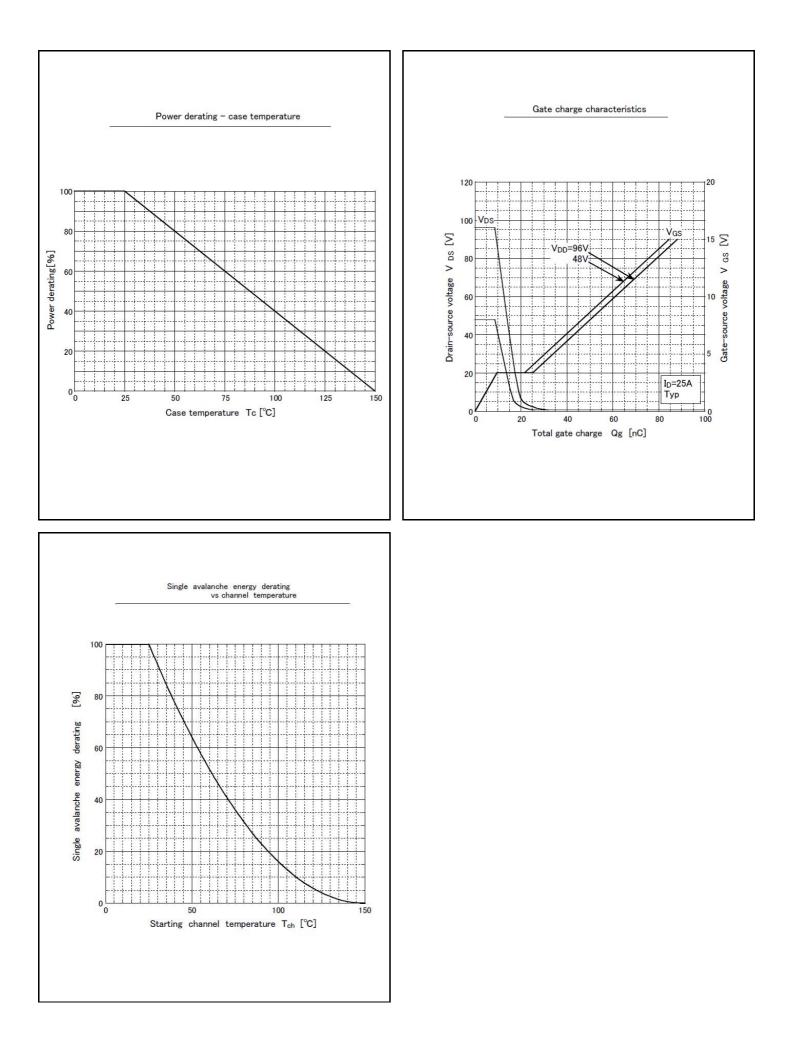


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Shindengen Electric Manufacturing Co., Ltd.

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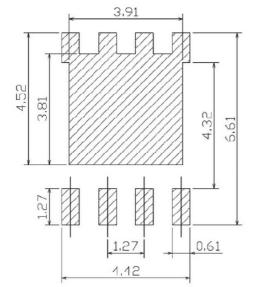
 0.51 ± 0.1

3.58±0.2

0.61±0.1

4

3.81-0.2 0.25±0.05 8 5 8 5 5,75±0,05 6±0,1 (0,25) (0,45) Ŧ 1 1 4 4 0.33-0.12 $0.41\substack{+0.1\\-0.08}$ 1,27 1±0.1 ▲ 2. 端子配置 3. 製品質量: 0.09g(標準) Lead Assignment Package Weight: 0.09g(typ) MOS-FET 123 : Source : Gate 4.9±0.1 5678 : Drain



UNIT: mm

Notes

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